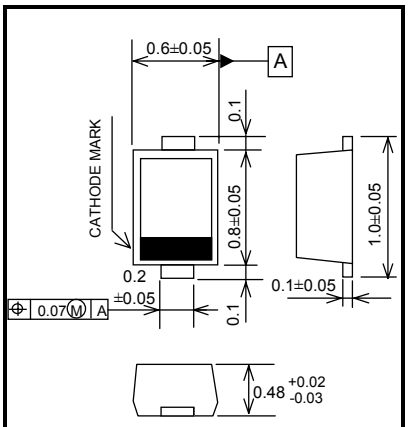
TOSHIBA Diode Silicon Epitaxial Schottky Barrier Type

1SS413

High Speed Switching Application

- Low forward voltage : $V_{F\ (3)}$ = 0.50V (typ.)
- Low reverse current : I_R= 0.5μA (max)
- Small total capacitance : C_T = 3.9pF (typ.)

Unit: mm



fSC

JEDEC	―
JEITA	―
TOSHIBA	1-1L1A

Weight:0.0006g(typ.)

Maximum Ratings (Ta = 25°C)

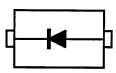
Characteristic	Symbol	Rating	Unit
Maximum (peak) reverse Voltage	V_{RM}	25	V
Reverse voltage	V_R	20	V
Maximum (peak) forward current	I_{FM}	100	mA
Average forward current	I_O	50	mA
Surge current (10ms)	I_{FSM}	1	A
Power dissipation	P *	100	mW
Junction temperature	T_j	125	°C
Storage temperature range	T_{stg}	−55~125	°C

* Mounted on a glass epoxy circuit board of 20 × 20 mm, pad dimension of 4 × 4 mm.

Electrical Characteristics (Ta = 25°C)

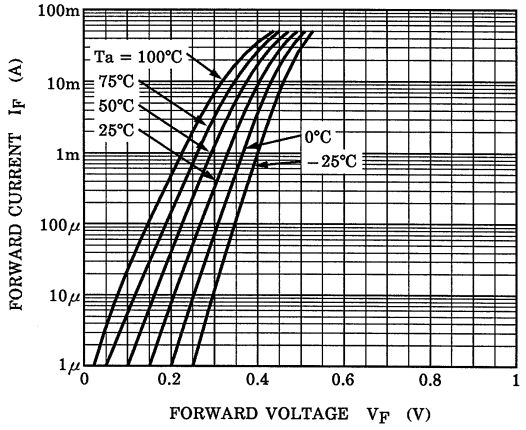
Characteristic	Symbol	Test Circuit	Test Condition	Min	Typ.	Max	Unit
Forward voltage	$V_{F\ (1)}$	―	I_F = 1mA	―	0.33	―	V
	$V_{F\ (2)}$	―	I_F = 5mA	―	0.38	―	
	$V_{F\ (3)}$	―	I_F = 50mA	―	0.50	0.55	
Reverse current	I_R	―	V_R = 20V	―	―	0.5	μA
Total capacitance	C_T	―	V_R = 0, f = 1MHz	―	3.9	―	pF

Equivalent Circuit (Top View)

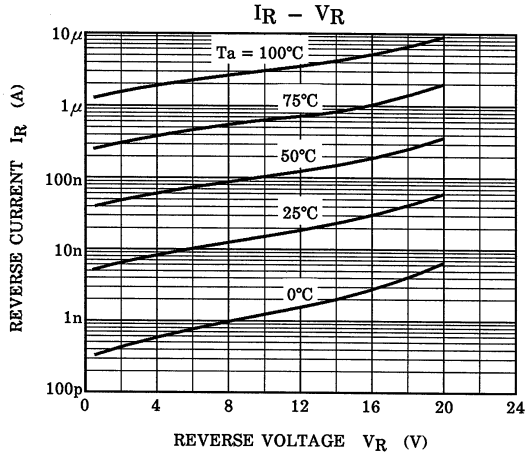


Marking

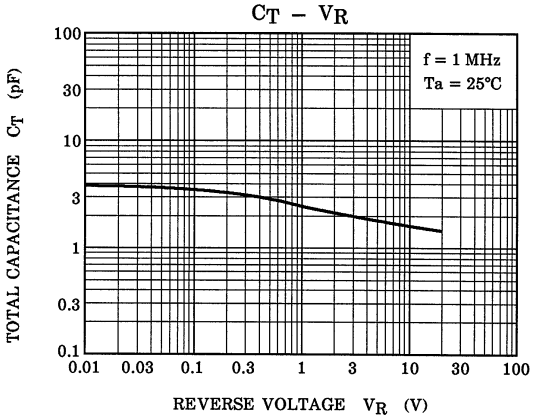
$I_F - V_F$



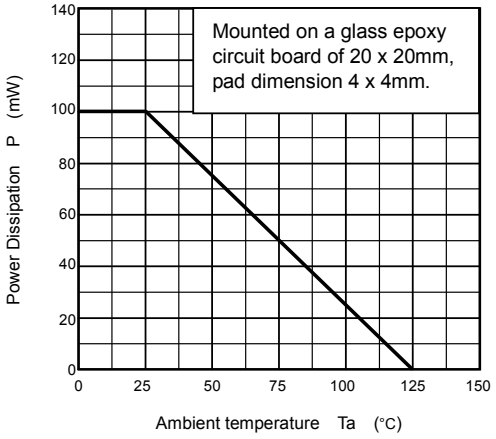
$I_R - V_R$



$C_T - V_R$



$P - T_a$



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